# The SPICE and HeRALD experiments for sub-GeV dark matter direct detection

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Scott Hertel, U. Massachusetts

### Dark Matter in the keV-MeV mass range

Consistent with simple thermal production after inflation (like other massive particles) Typically require a new force mediator too, not just the DM particle. Direct detection searches via electron scattering or nuclear scattering



https://science.osti.gov/-/media/hep/pdf/Reports/Dark\_Matter\_New\_Initiatives\_rpt.pdf https://physics.aps.org/articles/v13/172

### Putting the most sensitive sensors on the most interesting targets

Step 1: Push Transition Edge Sensors to even lower threshold



Step 2: Apply those sensors to diverse target materials with diverse signals





TES's are not too complicated, and have been around for a long time...





But dramatic improvement seems surprisingly accessible.

 $\sigma_{< E>} \propto \nu \nu$ 



- 1. Push the critical temperature as low as possible
- 2. Push the total TES volume as low as possible

1. Push the critical temperature as low as possible... done?

R/Rn



So... Tc is good, changing the volume is easy... are we ready for 1meV thresholds?

Once Tc and volume are low, it only takes femtoWatts or even attoWatts to drive the TES normal.

Extreme sensitivity to power is a double-edged sword!



Great, so now we're ready?

#### Next challenge: Spontaneous phonon emission

This is a challenge universal to low-threshold bolometer experiments, often called the "lowenergy excess" or the "heat-only events".



sensor hanging by wire bonds



Type 1: At mechanical interfaces (clamps)

Type 2: Intrinsic to stressed materials (TES films, Al films, substrate, ...)

Current activities: Back to film R&D, goal of producing films with minimal stress.





## Back to the big pictu

The main effort right now is red power and spontaneous phono

n<sup>3</sup> Polar Crys

РО

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#### Sensor R&D primarily on Si substrates



## But in parallel, we are starting to apply the initial sensors to some initial target materials





## Sapphire, aka Al<sub>2</sub>O<sub>3</sub> (part of SPICE)

Key attributes:

**1. Sapphire supports many optical phonon modes.** (phonons with a high energy:momentum ratio)

Instead thinking about 'kicking an atom' we now think about recoiling off the lattice, and 'exciting a phonon'.

Optical phonons are kinematically well-matched to low-mass dark matter (similar effective mass)

**2. Related: Sapphire is a polar crystal** (couples well to E&M-like inputs)





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## Sapphire, aka Al<sub>2</sub>O<sub>3</sub> (part of SPICE)

Development:

Design driver: Push threshold to single optical phonon scale, 10s of meV

TES fabrication on Sapphire now demonstrated!

Tc too low for current parasitic power levels... (no DM search data yet)



### superfluid <sup>4</sup>He target: HeRALD

#### **Sensitivity to Low-mass Dark Matter**

#### **Evaporation** Sensors

Primary channel (sets threshold)

QP focus

Immersed

Secondary channels

(aid discrimination)

(perhaps also low-

Excimer focus

energy QP)

Sensors

Comparatively low-mass nucleus (result: relatively high recoil energy endpoint) Signal gain (threshold reduction) through quantum evaporation then adsorption

#### Suppression/Rejection of Backgrounds

Many gan

Efficient e

No electro

#### **Complementarity with Crystal Target Materials**

He quasiparticles long-lived and balistic at relatively high energies (~1meV)

Vacuum gap separates target and phonon sensor: - QP must be highly-athermal to be sensed via evaporation - suppression of sensor backgrounds via coincidence requirement



#### arXiv:1810.06283

nmas simply pass through	(low-Z ma	aterial)
electron recoil tagging above	e~100eV	(using scintillation/excimers)
on recoils below 20eV	(He first ex	cited state)

### van der Waals gain

4He atom feels a ~9meV van der Waals potential at Si surface.

Simplistically: 1eV recoil energy in 4He becomes ~1000 rotons.... ~1000 rotons becomes ~1000 evaporated atoms... ~1000 evaporated atoms becoms ~1000 x 9meV = 9eV

Question: Can we further increase this ~9x "adsorption gain"?

We can increase this van der Waals gain by using..... polar crystal substrates! (perfect overlap with SPICE R&D)



## **Film-Stopping**

#### **Film Burner**

Well-demonstrated, by HERON R&D and others

Heat: some heatload on MC & sensor platform (remember, calorimeter threshold: T^3)

**Evaporation**: *some* gas leakage (aka 'dark counts')



Knife Edge

Demonstrated at higher temperatures...

We have made ~7nm radius devices...

#### Goal: Dry sensor, all parts of cell at MC temperature, no evaporation/condensation.









### HeRALD R&D cell at UMass



Primary driver: demonstrate Cs strategy for quantum evap. signals Secondary driver: serve as a flexible testbed for subsequent work

Clean division between 'dry' sensor platform/pillar, and 'wet' target region, walls, etc.

Ring of Cs dispensers surrounding pillar, defines boundary

Thermal modeling important to design, so that sensor can be baked dry (>10K), keeing 4He low vapor-pressure (<100mK).

AND sensor needs to cool down again to <10mK

Mixing Chamber

Large (20cm Ø) stainless cell, plenty of space to work inside (great for R&D, easy to change geometry)

Large amount of Cu within cell (~27kg !), based on four 1" plates.

- 'filler' material to define the 4He target region
- nearly 4pi gamma shield (we see ~0.7 Bq in the 10g of Si, pretty good)

Currently using single-channel TES array on 3-inch wafer. 4He target region: 6cm Ø















#### pull-away Cs leads



#### pinch-off pump-out port







![](_page_18_Picture_3.jpeg)

### First looks at the data... (very very preliminary)

We see two clearly distinct categories of large (saturating) events.

The population we call 'helium hits' are likely showing the decays of the long-lived triplet excimer population.

![](_page_19_Figure_3.jpeg)

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### First looks at the data... (very very preliminary)

How will quantum evaporation appear in our setup?

We include an 55Fe source shining down into the target (x-rays, ~6 keV)

sensor

![](_page_20_Figure_4.jpeg)

1. prompt scintillation

~2keV of photons before solid angle... (roughly 1keV at top and 0.5keV at bottom)

#### 2. Evaporation delayed by $\Delta t = depth/vel$ .

~2cm target thickness, ~200m/s R+ velocity...  $\dots$  expect  $\Delta t$  scale of order 100µs timing

![](_page_20_Figure_9.jpeg)

![](_page_20_Figure_12.jpeg)

### First looks at the data... (very very preliminary)

#### **Observations not far from expectation!**

#### -Clear population of double-pulses at the energies we expect for 55Fe

-Broad distribution in  $\Delta t$  out to a 'cliff' of ~240µs (seen in both the 55Fe population and our gamma backgrounds)

#### -Anti-correlation seen as expected from solid angle (prompt smaller when $\Delta t$ bigger)

![](_page_21_Figure_5.jpeg)

A collection of similar-sized pulses

![](_page_21_Figure_8.jpeg)

### Summary

![](_page_22_Picture_2.jpeg)

![](_page_22_Picture_3.jpeg)

![](_page_22_Picture_4.jpeg)

![](_page_22_Picture_5.jpeg)

- Sapphire is a compelling DM target material

Lots of work going on, lots of exciting progress on all fronts!

-TESs now have the goal Tc, goal power sensitivity -Next step: remove sources of parasitic power and phonons

-Single optical phonon sensitivity appears within reach

-Superfluid 4He is also a compelling DM target material -Now studying and optimizing evaporation signals